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5 October 2015

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Dear Sirs

**International Patent Application No PCT/GB2015/051478**  
**Dielectric materials for low voltage OFET operation**  
**The University of Manchester**

In connection with the above patent application, we enclose a replacement declaration which has been signed and dated by the inventors, Michael L. TURNER, Sheida FARAJI and Leszek MAJEWSKI.

Yours faithfully

*Nathan Hinks*

**Nathan Hinks**  
**for and on behalf of HGF Limited**  
**Agents for the Applicant**

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